










	<p>Manufacturer Part Number: IPD50R1K4CEBTMA1</p>
	<p>Manufacturer/Brand: International Rectifier (Infineon Technologies)</p>
	<p>Part of Description: MOSFET N-CH 500V 3.1A PG-TO-252</p>
	<p>Datasheets:  IPD50R1K4CEBTMA1.pdf</p>
	<p>RoHs Status:  Lead free / RoHS</p>
	<p>Stock Condition: Compliant New original, Stock Available.</p>
	<p>Ship From: Hong Kong</p>
<p>Image may be representation. See specs for product details.</p>	<p>Shipment Way: DHL/Fedex/TNT/UPS/EMS</p>

Specifications

Part Number	IPD50R1K4CEBTMA1
Manufacturer	International Rectifier (Infineon Technologies)
Description	MOSFET N-CH 500V 3.1A PG-TO-252
Category	Discrete Semiconductor Products > Transistors - FETs,
Part Status	Require For Quote & Check Stock
Vgs(th) (Max) @ Id	3.5V @ 70µA
Vgs (Max)	±20V
Technology	MOSFET (Metal Oxide)
Supplier Device Package	PG-TO252-3
Series	CoolMOS™ CE
Rds On (Max) @ Id, Vgs	1.4 Ohm @ 900mA, 13V
Power Dissipation (Max)	25W (Tc)
Packaging	Tape & Reel (TR)
Package / Case	TO-252-3, DPak (2 Leads + Tab), SC-63
Operating Temperature	-55°C ~ 150°C (TJ)
Mounting Type	Surface Mount
Input Capacitance (Ciss) (Max) @ Vds	178pF @ 100V
Gate Charge (Qg) (Max) @ Vgs	1nC @ 10V
FET Type	N-Channel
FET Feature	-
Drive Voltage (Max Rds On, Min Rds On)	13V
Drain to Source Voltage (Vdss)	500V
Current - Continuous Drain (Id) @ 25°C	3.1A (Tc)

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